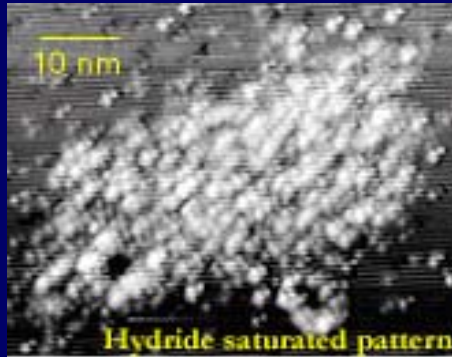
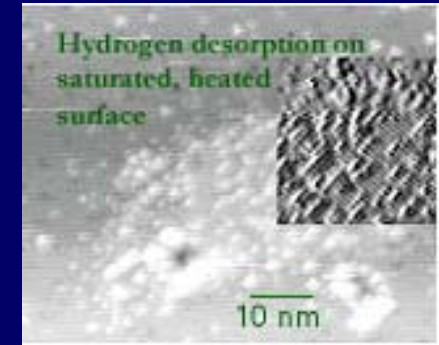


# Selective Silicon Epitaxy Seen at the Nanometer Scale



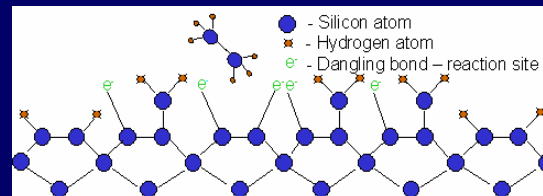
**Matthew M. Sztelle**

sztelle@uiuc.edu



Research Assistant for Professor Joe Lyding

Scanning Tunneling Microscopy Group: Beckman Institute  
University of Illinois Urbana-Champaign



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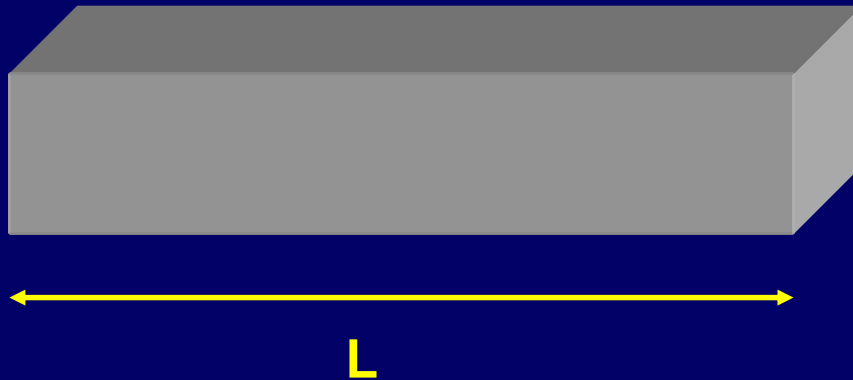
# Outline

- Motivation for NEMS
- Scanning Tunneling Microscopy and its role
- Silicon epitaxy temperature dependency
- Vacancy diffusion
- Nanometer scale epitaxy

# NEMS: Nanoelectromechanical Systems

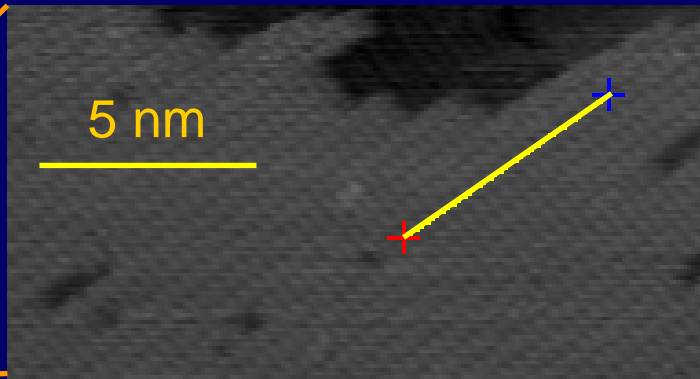
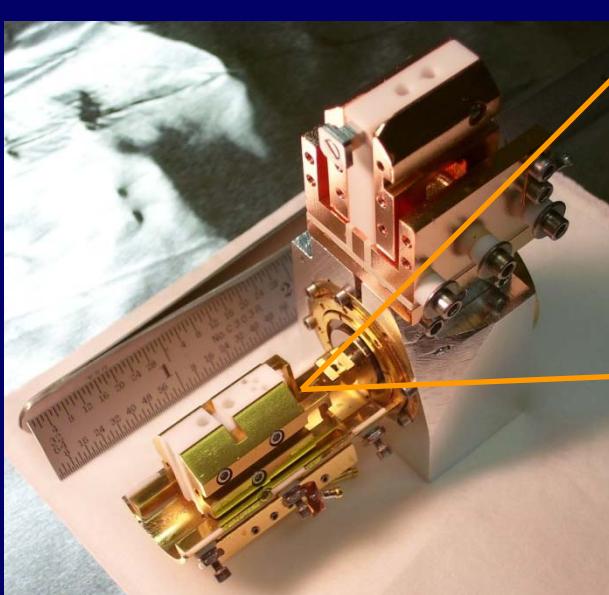
Allow physical phenomena to be coupled with integrated circuits

Cantilever:

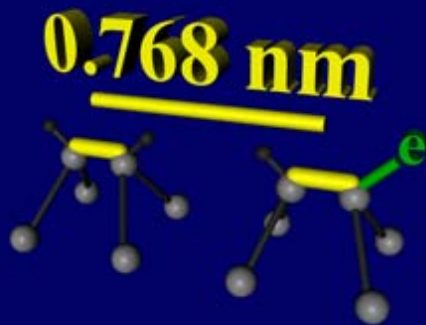
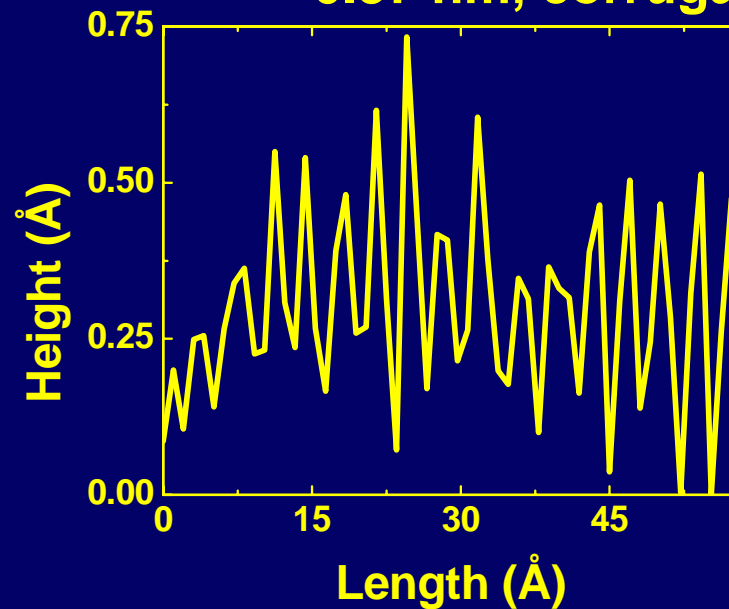


$$f_0 \propto \frac{1}{L^2}$$

# Scanning Tunneling Microscopy (STM): Ideal for Nanometer-Scale Work



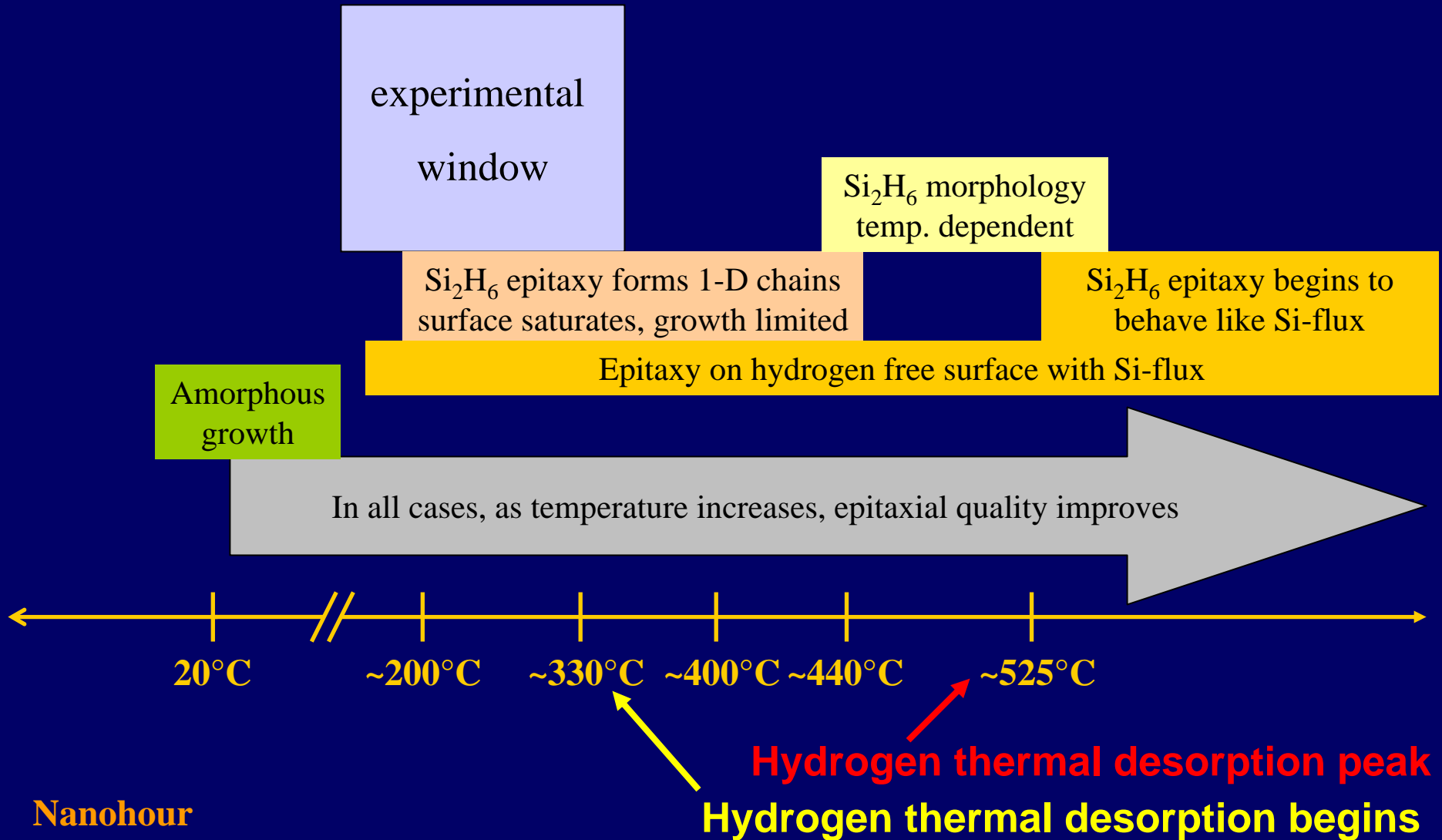
~ 0.37 nm, corrugation



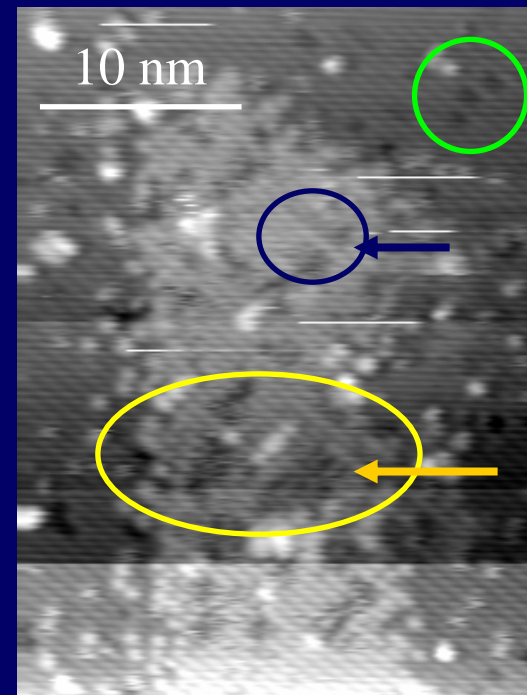
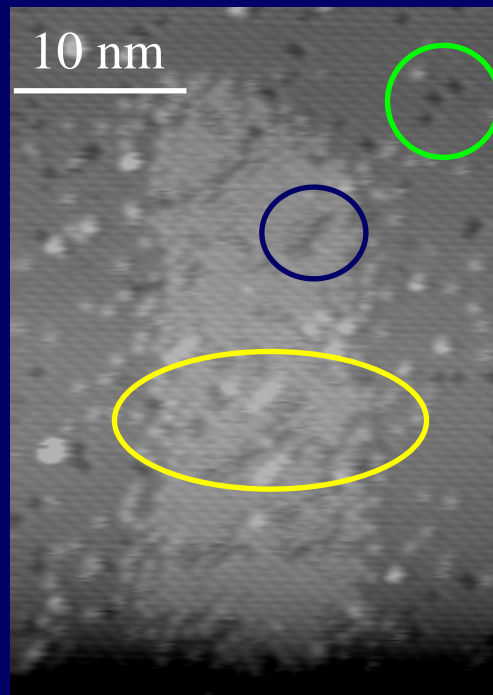
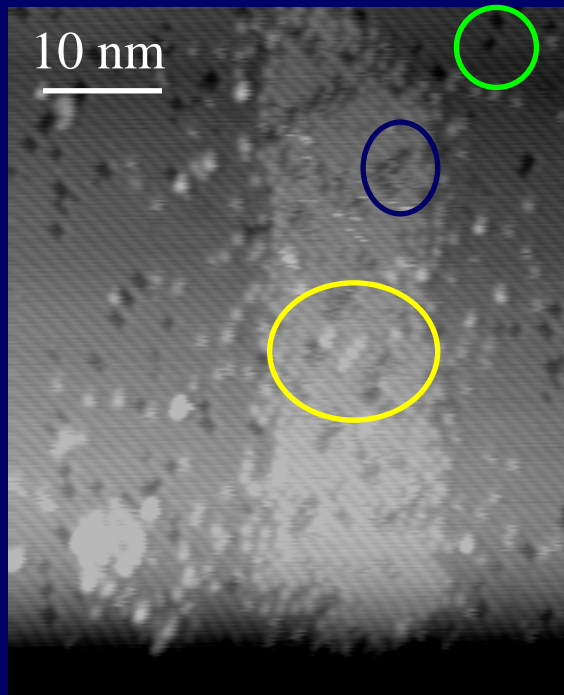
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# Epitaxy Temperature Dependency

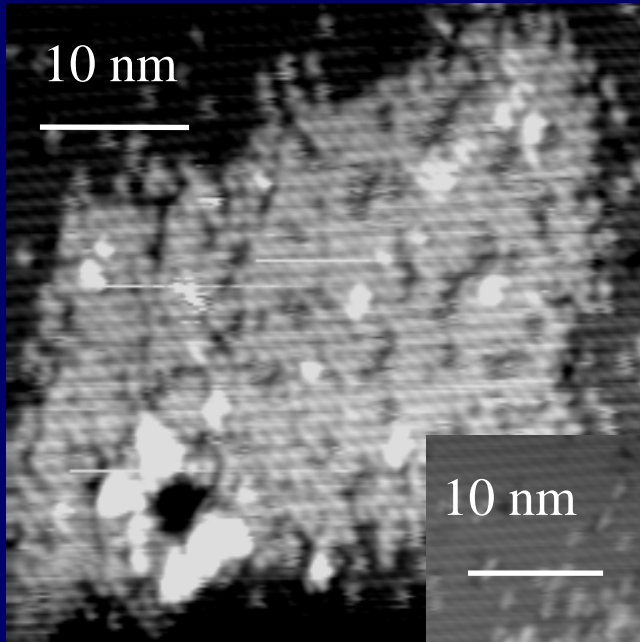


# Surface Phenomena at 220°C: No disilane

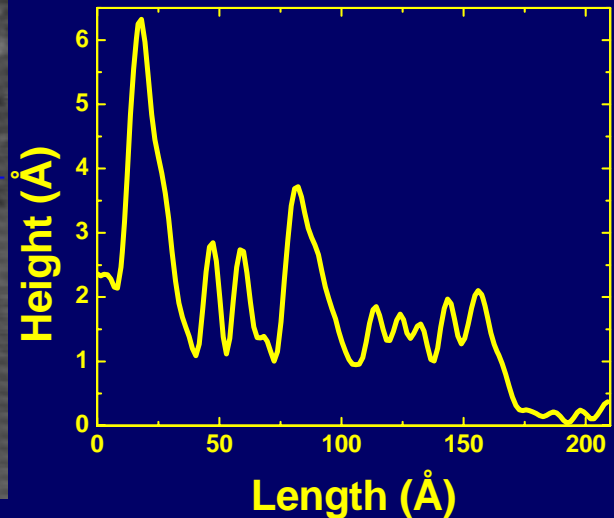
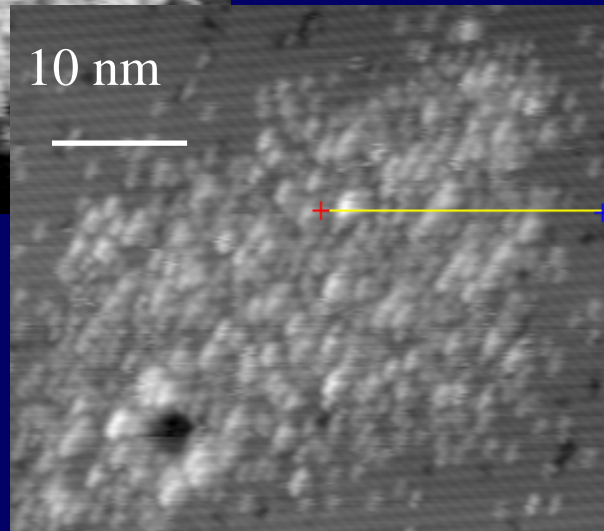
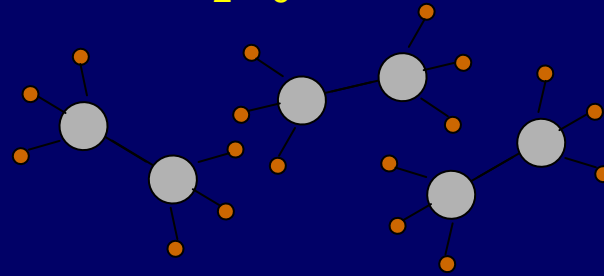


- This behavior is NOT observed at room temperature

# Silicon Epitaxy – Initial Patterning & Saturation



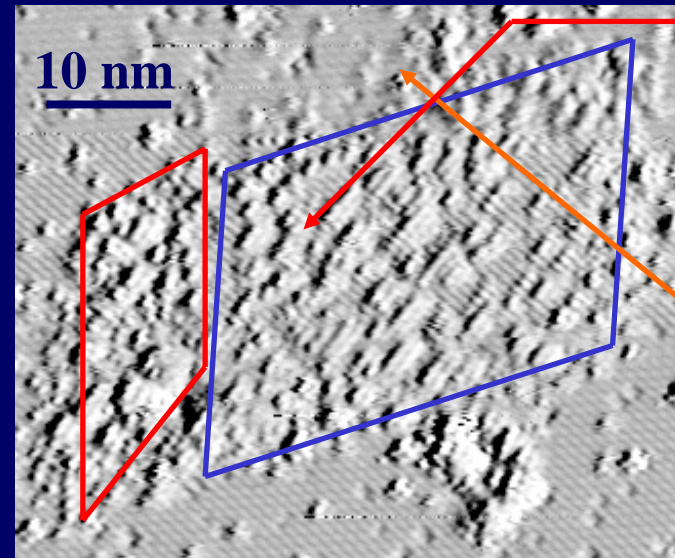
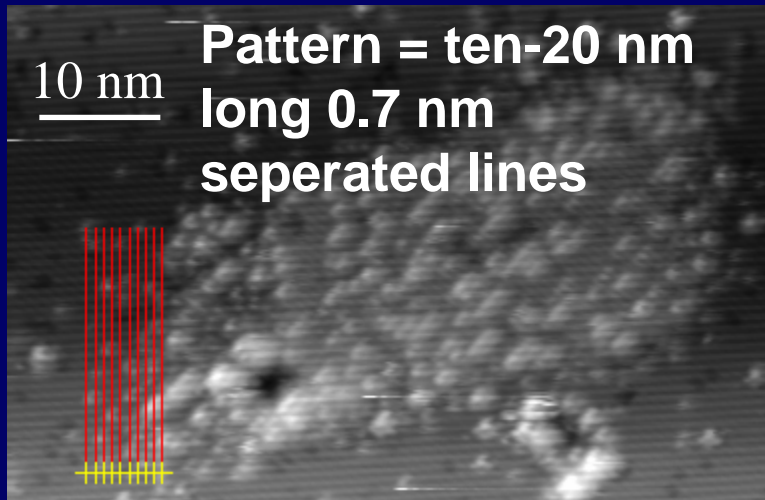
Disilane:  $\text{Si}_2\text{H}_6$  -  $5 \times 10^{-9}$  Torr



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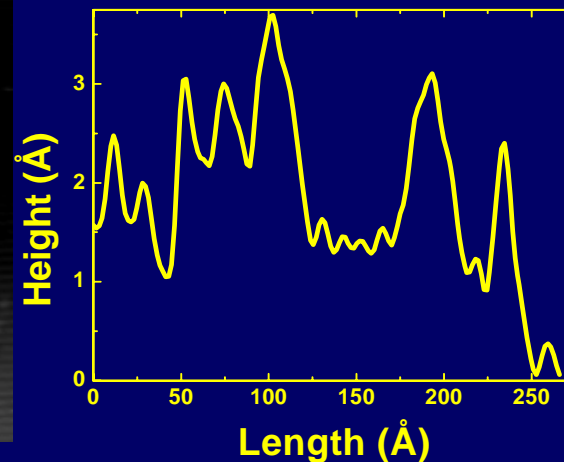
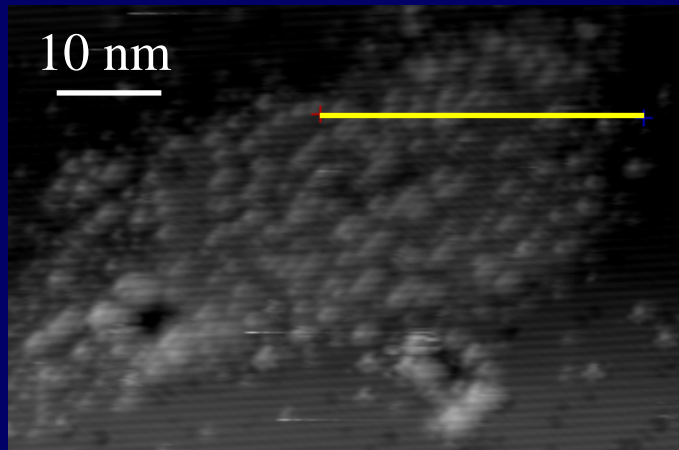
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# 1-D Dimer Chain Formation After Hydrogen Removal



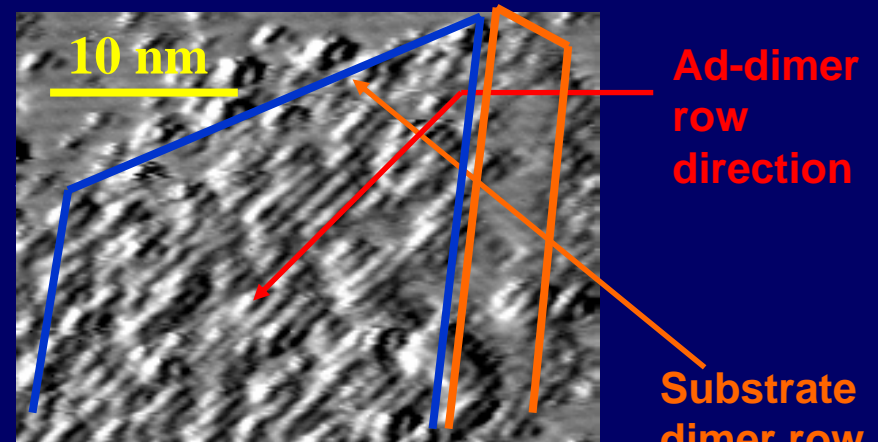
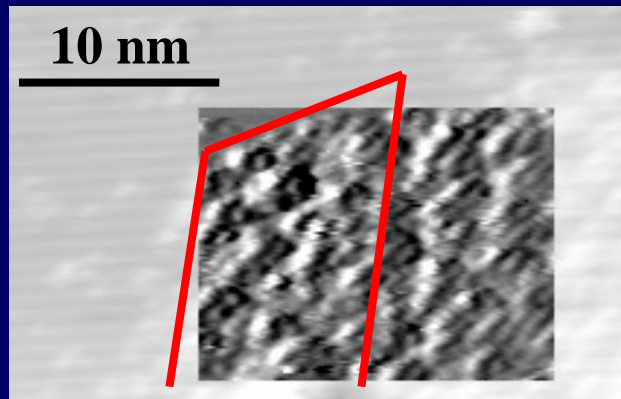
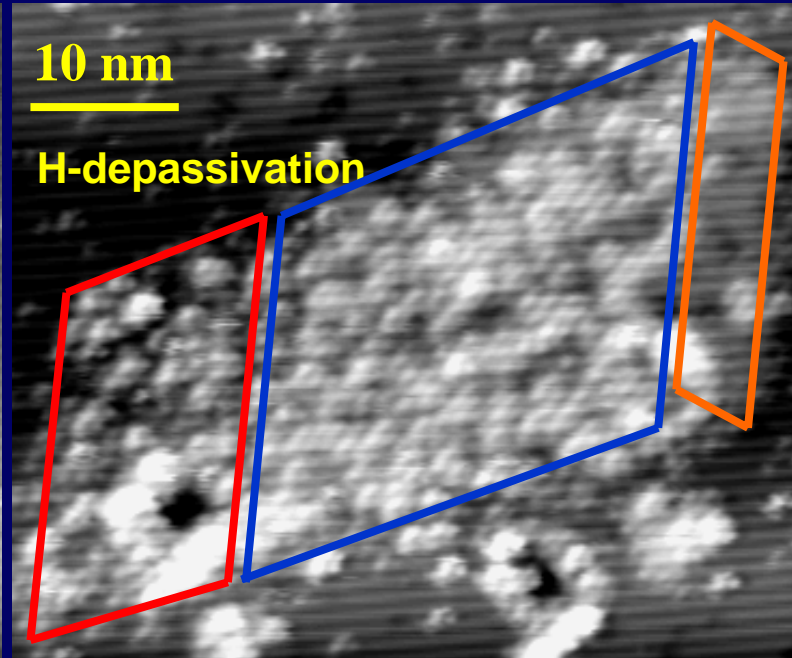
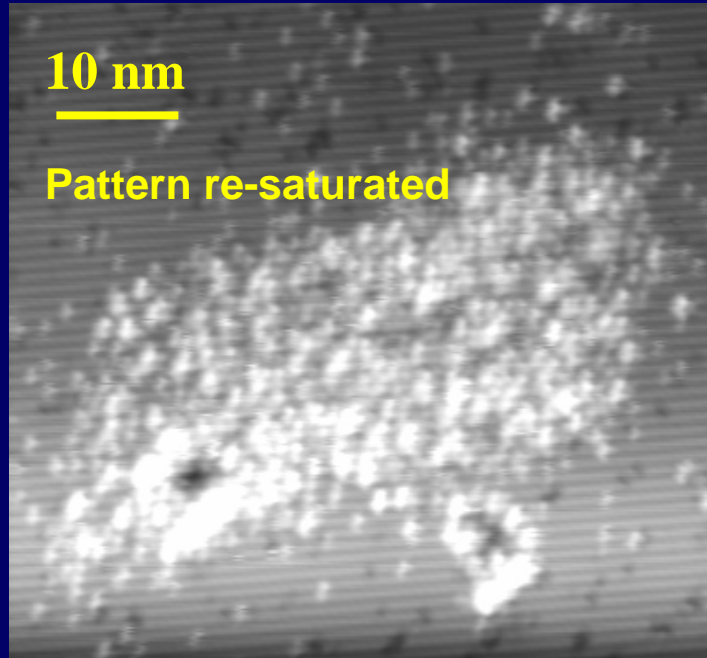
Ad-dimer  
row  
direction

Substrate  
dimer  
row  
direction



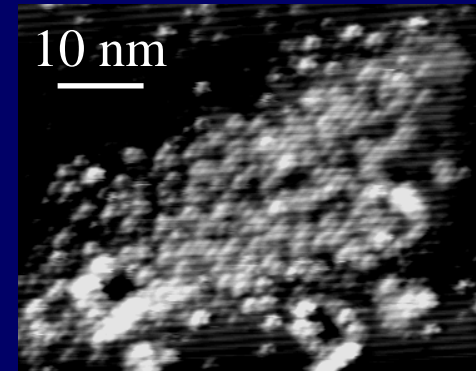
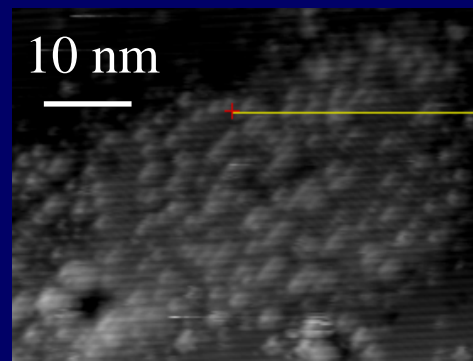
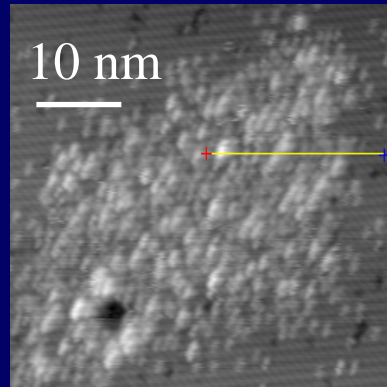
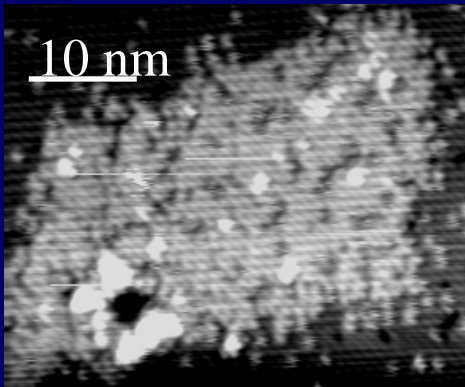


# Increasing Pattern Coverage



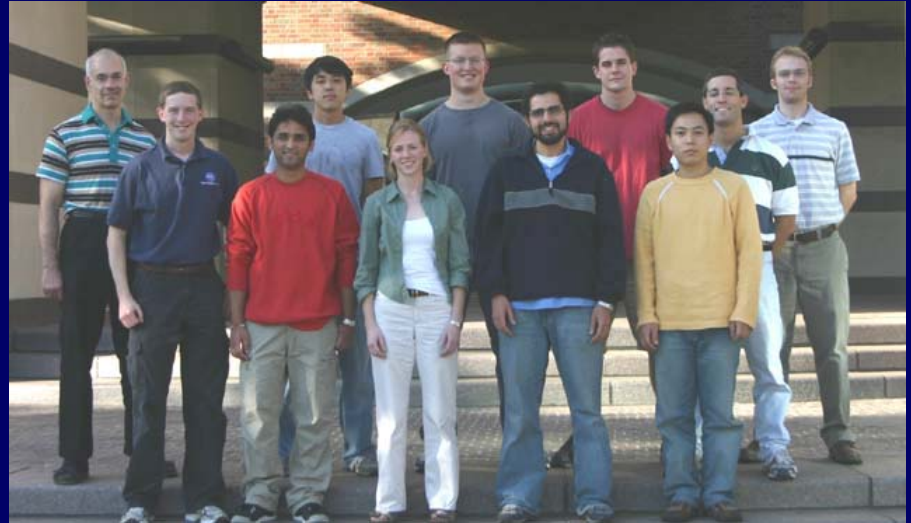
# Conclusion

- Demonstrated nanoscale selective patterning on the hydrogen-passivated Si(100) surface at elevated temperatures
- Deposited silicon-hydride and hydrogen species on pattern
- Removed hydrogen and saw 1-D dimer chain formation
- Repeating process increased surface coverage



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